

Low Dropout Fixed Voltage Regulator

TLE42994GMV33 TLE42994EV33

Data Sheet

Rev. 1.01, 2010-10-14

Automotive Power



Low Dropout Fixed Voltage Regulator

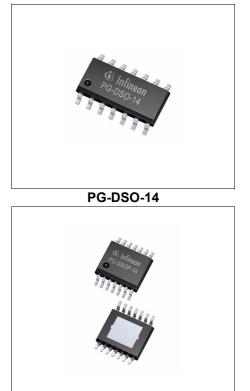
TLE42994GMV33



1 Overview

Features

- Output Voltage 3.3 V \pm 2%
- Ouput Current up to 150 mA
- Extreme Low Current Consumption In ON State
- Enable Function: Below 1 µA Current Consumption In OFF State
- Early Warning
- · Power-on and Undervoltage Reset with Programmable Delay Time
- Reset Low Down to $V_{\rm Q}$ = 1 V
- Adjustable Reset Threshold
- Very Low Dropout Voltage
- Output Current Limitation
- Reverse Polarity Protection
- Overtemperature Protection
- Suitable for Use in Automotive Electronics
- Wide Temperature Range from -40 °C up to 150 °C
- Input Voltage Range from -40 V to 45 V
- Green Product (RoHS compliant)
- AEC Qualified



PG-SSOP-14 Exposed Pad

Description

The TLE42994V33 is a monolithic integrated low dropout voltage regulator, especially designed for automotive applications that need to be in ON state during the car's engine is turned off. An input voltage up to 45 V is regulated to an output voltage of 3.3 V. The component is able to drive loads up to 150 mA. It is short-circuit protected by the implemented current limitation and has an integrated overtemperature shutdown. A reset signal is generated for an output voltage $V_{Q,rt}$ of typically 3.1 V. This threshold can be decreased by an external resistor divider. The power-on reset delay time can be programmed by the external delay capacitor. The additional sense comparator provides an early warning function: Any voltage (e.g. the input voltage) can be monitored, an undervoltage condition is indicated by setting the comparator's output to low. Additionally, an Enable function permitting enabling/disabling the regulator is also included. In case the regulator is disabled it consumes less current than 1 μ A.

Туре	Package	Marking
TLE42994GMV33	PG-DSO-14	42994GMV33
TLE42994EV33	PG-SSOP-14 Exposed Pad	42994EV33



Overview

Dimensioning Information on External Components

The input capacitor C_1 is recommended for compensation of line influences. The output capacitor C_Q is necessary for the stability of the control loop.

Circuit Description

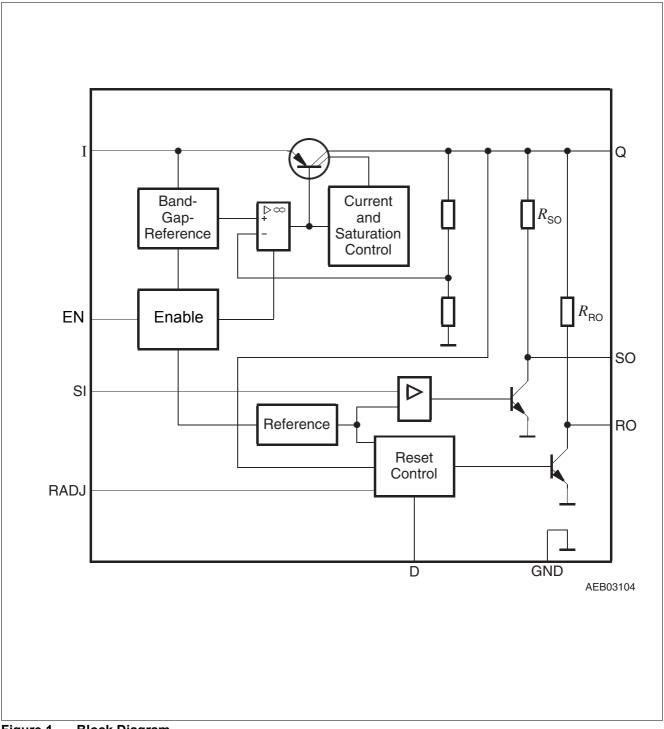
The control amplifier compares a reference voltage to a voltage that is proportional to the output voltage and drives the base of the series transistor via a buffer. Saturation control as a function of the load current prevents any oversaturation of the power element. The component also has a number of internal circuits for protection against:

- Overload
- Overtemperature
- Reverse polarity



Block Diagram

2 Block Diagram







Pin Configuration

3 Pin Configuration

3.1 Pin Assignment TLE42994GMV33 (PG-DSO-14)

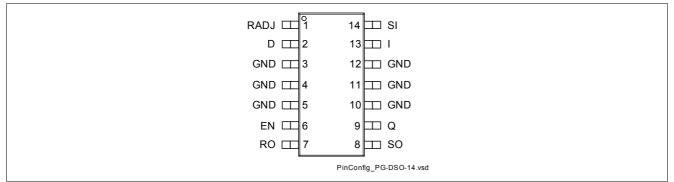


Figure 2 Pin Configuration (top view)

3.2 Pin Definitions and Functions TLE42994GMV33 (PG-DSO-14)

Pin	Symbol	Function
1	RADJ	Reset Threshold Adjust connect an external voltage divider to adjust reset threshold; connect to GND for using internal threshold
2	D	Reset Delay Timing connect a ceramic capacitor to GND for adjusting the reset delay time; leave open if the reset function is not needed
3, 4, 5	GND	Ground connect all pins to PCB and heatsink area
6	EN	Enable high signal enables the regulator; low signal disables the regulator; connect to I if the Enable function is not needed
7	RO	Reset Output open collector output; internally linked to the output via a $20k\Omega$ pull-up resistor; leave open if the reset function is not needed
8	SO	Sense Output open collector output; internally linked to the output via a $20k\Omega$ pull-up resistor; leave open if the sense comparator is not needed
9	Q	Outputblock to GND with a capacitor close to the IC terminals, respecting the values givenfor its capacitance C_Q and ESR in the table "Functional Range" on Page 8
10, 11, 12	GND	Ground connect all pins to PCB and heatsink area
13	I	Input for compensating line influences, a capacitor to GND close to the IC terminals is recommended
14	SI	Sense Input connect the voltage to be monitored; connect to Q if the sense comparator is not needed



Pin Configuration

3.3 Pin Assignment TLE42994EV33 (PG-SSOP-14 Exposed Pad)

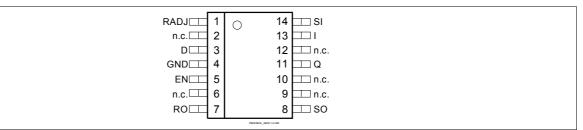


Figure 3 Pin Configuration (top view)

3.4 Pin Definitions and Functions TLE42994EV33 (PG-SSOP-14 Exposed Pad)

Pin	Symbol	Function
1	RADJ	Reset Threshold Adjust connect an external voltage divider to adjust reset threshold; connect to GND for using internal threshold
2, 6	n.c.	not connected leave open or connect to GND
3	D	Reset Delay Timing connect a ceramic capacitor to GND for adjusting the reset delay time; leave open if the reset function is not needed
4	GND	Ground connect all pins to PCB and heatsink area
5	EN	Enable high signal enables the regulator; low signal disables the regulator; connect to I if the Enable function is not needed
7	RO	Reset Output open collector output; internally linked to the output via a $20k\Omega$ pull-up resistor; leave open if the reset function is not needed
8	SO	Sense Output open collector output; internally linked to the output via a $20k\Omega$ pull-up resistor; leave open if the sense comparator is not needed
9, 10, 12	n.c.	not connected leave open or connect to GND
11	Q	Output block to GND with a capacitor close to the IC terminals, respecting the values given for its capacitance C_Q and ESR in the table "Functional Range" on Page 8
13	I	Input for compensating line influences, a capacitor to GND close to the IC terminals is recommended
14	SI	Sense Input connect the voltage to be monitored; connect to Q if the sense comparator is not needed
PAD	-	Exposed Pad attach the exposed pad on package bottom to the heatsink area on circuit board; connect to GND



4 General Product Characteristics

4.1 Absolute Maximum Ratings

Absolute Maximum Ratings ¹⁾

-40 °C \leq T_j \leq 150 °C; all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Pos.	Parameter	Symbol	Limit Values		Unit	Conditions
			Min.	Max.		
Input I,	Enable Input EN, Sense Input SI					-
4.1.1	Voltage	$V_{ m I}, V_{ m EN}, V_{ m SI}$	-40	45	V	-
Output	Q, Reset Output RO, Sense Outp	out SO				
4.1.2	Voltage	$V_{ m Q}, V_{ m RO}, \ V_{ m SO}$	-0.3	7	V	-
Reset I	Delay D, Reset Threshold RADJ		-	H		_
4.1.3	Voltage	$V_{\sf D}$, $V_{\sf RADJ}$	-0.3	7	V	-
Tempe	rature		-	H		_
4.1.4	Junction Temperature	Ti	-40	150	°C	-
4.1.5	Storage Temperature	T _{stg}	-50	150	°C	-
ESD A	osorption		-	H		_
4.1.6	ESD Absorption	$V_{\rm ESD,HBM}$	-2	2	kV	Human Body Model (HBM) ²⁾
4.1.7		$V_{\rm ESD,CDM}$	-500	500	V	Charge Device Model (CDM) ³⁾
4.1.8			-750	750	V	Charge Device Model (CDM) ³⁾ at corner pins

1) not subject to production test, specified by design

2) ESD susceptibility Human Body Model "HBM" according to AEC-Q100-002 - JESD22-A114

3) ESD susceptibility Charged Device Model "CDM" according to ESDA STM5.3.1

Note: Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note: Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.



General Product Characteristics

4.2 Functional Range

Pos.	Parameter	Symbol	Lin	nit Values	Unit	Conditions
			Min.	Max.		
4.2.1	Input Voltage	$V_{\rm I}$	4.4	45	V	-
4.2.2	Output Capacitor's Requirements	CQ	22	-	μF	_1)
	for Stability	$ESR(C_Q)$	_	3	Ω	_2)
4.2.3	Junction Temperature	Tj	-40	150	°C	-

1) the minimum output capacitance requirement is applicable for a worst case capacitance tolerance of 30%

2) relevant ESR value at f = 10 kHz

Note: Within the functional range the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the related electrical characteristics table.

4.3 Thermal Resistance

Pos.	Parameter	Symbol	L	imit Va	lue	Unit	Conditions
			Min.	Тур.	Max.		
TLE429	994GMV33 (PG-DSO-14)	I			1		
4.3.1	Junction to Soldering Point ¹⁾	R_{thJSP}	-	-	30	K/W	measured to pin 5
4.3.2	Junction to Ambient ¹⁾	R _{thJA}	-	63	-	K/W	2)
4.3.3	_		-	112	-	K/W	Footprint only ³⁾
4.3.4			-	73	-	K/W	300mm ² heatsink area on PCB ³⁾
4.3.5	_		-	65	-	K/W	600mm ² heatsink area on PCB ³⁾
TLE429	994EV33 (PG-SSOP-14 Exposed	Pad)					
4.3.6	Junction to Soldering Point ¹⁾	R_{thJSP}	-	10	-	K/W	measured to all GND pins
4.3.7	Junction to Ambient ¹⁾	R _{thJA}	-	47	_	K/W	2)
4.3.8	_		_	140	_	K/W	Footprint only ³⁾
4.3.9	_		-	63	-	K/W	300mm ² heatsink area on PCB ³⁾
4.3.10	_		-	53	-	K/W	600mm ² heatsink area on PCB ³⁾

1) not subject to production test, specified by design

 Specified R_{thJA} value is according to Jedec JESD51-2,-5,-7 at natural convection on FR4 2s2p board; The Product (Chip+Package) was simulated on a 76.2 x 114.3 x 1.5 mm³ board with 2 inner copper layers (2 x 70µm Cu, 2 x 35µm Cu). Where applicable a thermal via array under the exposed pad contacted the first inner copper layer.

3) Specified R_{thJA} value is according to JEDEC JESD 51-3 at natural convection on FR4 1s0p board; The Product (Chip+Package) was simulated on a 76.2 × 114.3 × 1.5 mm³ board with 1 copper layer (1 x 70µm Cu).



5 Block Description and Electrical Characteristics

5.1 Voltage Regulator

The output voltage $V_{\rm Q}$ is controlled by comparing a portion of it to an internal reference and driving a PNP pass transistor accordingly. The control loop stability depends on the output capacitor $C_{\rm Q}$, the load current, the chip temperature and the poles/zeros introduced by the integrated circuit. To ensure stable operation, the output capacitor's capacitance and its equivalent series resistor ESR requirements given in the table "Functional Range" on Page 8 have to be maintained. For details see also the typical performance graph "Output Capacitor Series Resistor ESR(C_Q) versus Output Current I_Q" on Page 12. As the output capacitor also has to buffer load steps it should be sized according to the application's needs.

An input capacitor C_1 is strongly recommended to compensate line influences. Connect the capacitors close to the component's terminals.

A protection circuitry prevents the IC as well as the application from destruction in case of catastrophic events. These safeguards contain an output current limitation, a reverse polarity protection as well as a thermal shutdown in case of overtemperature.

To avoid excessive power dissipation that could never be handled by the pass element and the package, the maximum output current is decreased at input voltages above $V_1 = 22$ V.

The overtemperature shutdown circuit prevents the IC from immediate destruction under fault conditions (e.g. output continuously short-circuited) by switching off the power stage. After the chip has cooled down, the regulator restarts. This leads to an oscillatory behaviour of the output voltage until the fault is removed. However, junction temperatures above 150 °C are outside the maximum ratings and therefore significantly reduce the IC's lifetime.

The TLE42994V33 allows a negative supply voltage. In this fault condition, small currents are flowing into the IC, increasing its junction temperature. This has to be considered for the thermal design, respecting that the thermal protection circuit is not operating during reverse polarity conditions.

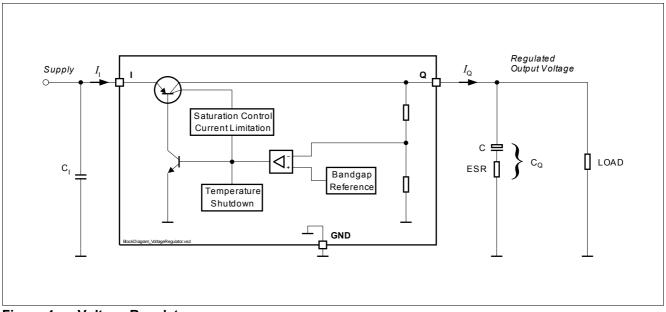


Figure 4 Voltage Regulator



Electrical Characteristics Voltage Regulator

 V_{l} = 13.5 V, -40 °C $\leq T_{j} \leq$ 150 °C, all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Pos.	Parameter	Symbol		Limit Values			Conditions
			Min.	Тур.	Max.		
5.1.1	Output Voltage	VQ	3.23	3.30	3.37	V	100 μ A < I_Q < 100 mA 5.5 V < V_I < 18 V
5.1.2			3.20	3.30	3.40	V	100 μ A < I_Q < 150 mA 5.5 V < V_I < 18 V
5.1.3	Output Current Limitation	$I_{\rm Q,max}$	150	400	500	mA	1)
5.1.4	Load Regulation steady-state	$\Delta V_{\rm Q,load}$	-30	-5	-	mV	$I_{\rm Q}$ = 1 mA to 100 mA $V_{\rm I}$ = 6 V
5.1.5	Line Regulation steady-state	$\Delta V_{\rm Q,line}$	-	10	25	mV	V_1 = 6 V to 32 V I_Q = 1 mA
5.1.6	Overtemperature Shutdown Threshold	$T_{\rm j,sd}$	151	-	200	°C	$T_{\rm j}$ increasing ²⁾
5.1.7	Overtemperature Shutdown Threshold Hysteresis	$T_{\rm j,sdh}$	-	15	-	°C	$T_{\rm j}$ decreasing ²⁾
5.1.8	Power Supply Ripple Rejection ²⁾	PSRR	-	66	-	dB	f_{ripple} = 100 Hz V_{ripple} = 1 Vpp I_Q = 100 mA

1) measured when the output voltage $V_{\rm Q}$ has dropped 100mV from the nominal value obtained at 13.5V

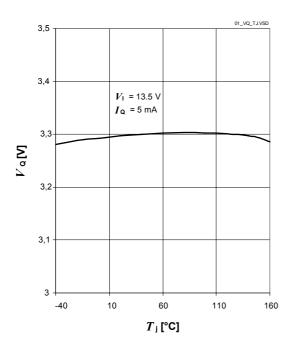
2) not subject to production test, specified by design



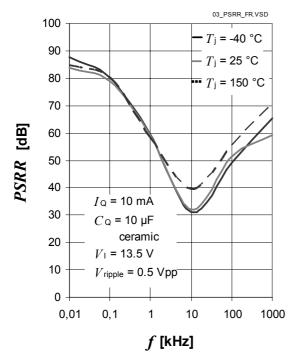
Block Description and Electrical Characteristics

5.2 Typical Performance Characteristics Voltage Regulator

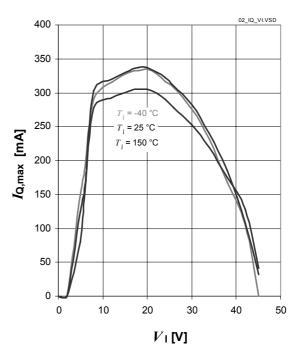




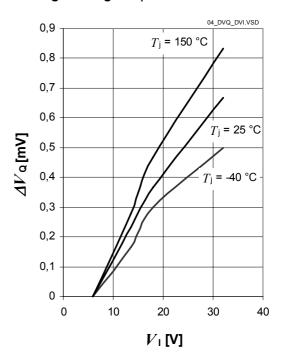
Power Supply Ripple Rejection PSRR versus ripple frequency f_r



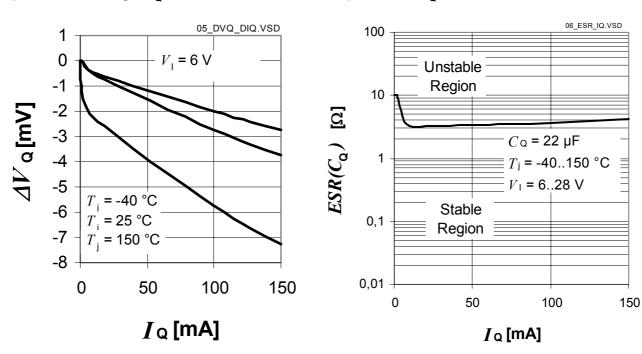
Output Current $I_{\rm Q}$ versus Input Voltage $V_{\rm I}$



Line Regulation $\Delta V_{\mathbf{Q},\text{line}}$ versus Input Voltage Change $\Delta V_{\mathbf{I}}$







Load Regulation $\Delta V_{Q,load}$ versus Output Current Change ΔI_{o}

5.3 **Current Consumption**

Electrical Characteristics Voltage Regulator

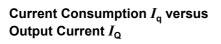
 $V_{\rm I}$ = 13.5 V, -40 °C $\leq T_{\rm i} \leq$ 150 °C, all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

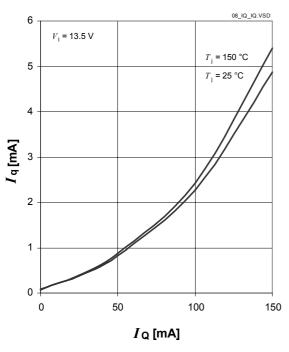
Pos.	Parameter	Symbol	I	Limit Val	ues	Unit	Conditions	
			Min.	Тур.	Max.			
5.3.1	Current Consumption $I_q = I_1 - I_Q$	Iq	-	-	1	μA	$V_{\rm EN}$ = 0 V $T_{\rm j}$ = 25 °C	
5.3.2			-	65	100	μA	Enable HIGH I_Q = 100 µA T_j = 25 °C	
5.3.3				-	65	105	μA	Enable HIGH I_Q = 100 µA $T_j \le 85 \text{ °C}$
5.3.4			-	0.17	0.5	mA	Enable HIGH $I_{\rm Q}$ = 10 mA	
5.3.5			-	0.7	2	mA	Enable HIGH $I_{\rm Q}$ = 50 mA	

Output Capacitor Series Resistor $ESR(C_{o})$ versus Output Current Io

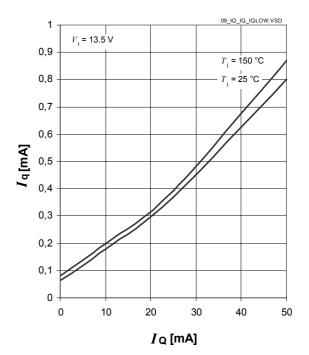


5.4 Typical Performance Characteristics Current Consumption

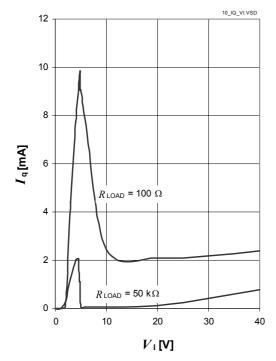




Current Consumption $I_{\rm q}$ versus Output Current $I_{\rm Q}$ ($I_{\rm Q}$ low)



Current Consumption $I_{\rm q}$ versus Input Voltage $V_{\rm l}$





5.5 Enable Function

Electrical Characteristics Voltage Regulator

 V_1 = 13.5 V, -40 °C $\leq T_j \leq$ 150 °C, all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Pos.	Parameter	Symbol	Limit Values			Unit	Conditions
			Min.	Тур.	Max.		
5.5.1	Enable OFF Voltage Range	$V_{EN,OFF}$	-	-	0.8	V	-
5.5.2	Enable ON Voltage Range	$V_{\rm EN,ON}$	3.5	-	-	V	-
5.5.3	Enable OFF Input Current	$I_{EN,OFF}$	-	0.5	2	μA	V _{EN} = 0 V
5.5.4	Enable ON Input Current	$I_{\rm EN,ON}$	-	3	5	μA	V _{EN} = 5 V

5.6 Reset Function

The reset function provides several features:

Output Undervoltage Reset:

An output undervoltage condition is indicated by setting the Reset Output RO to "low". This signal might be used to reset a microcontroller during low supply voltage.

Power-On Reset Delay Time:

The power-on reset delay time t_{rd} allows a microcontoller and oscillator to start up. This delay time is the time frame from exceeding the reset switching threshold V_{RT} until the reset is released by switching the reset output "RO" from "low" to "high". The power-on reset delay time t_{rd} is defined by an external delay capacitor C_D connected to pin D charged by the delay capacitor charge current $I_{D,ch}$ starting from $V_D = 0$ V.

If the application needs a power-on reset delay time t_{rd} different from the value given in **Item 5.6.9**, the delay capacitor's value can be derived from the specified values in **Item 5.6.9** and the desired power-on delay time:

$$C_{D} = \frac{t_{rd, new}}{t_{rd}} \times 100 nF$$

with

- $C_{\rm D}$: capacitance of the delay capacitor to be chosen
- *t*_{rd,new}: desired power-on reset delay time
- *t*_{rd}: power-on reset delay time specified in this datasheet

For a precise calculation also take the delay capacitor's tolerance into consideration.



Reset Reaction Time:

The reset reaction time avoids that short undervoltage spikes trigger an unwanted reset "low" signal. The reset reaction rime $t_{\rm rr}$ considers the internal reaction time $t_{\rm rr,int}$ and the discharge time $t_{\rm rr,d}$ defined by the external delay capacitor $C_{\rm D}$ (see typical performance graph for details). Hence, the total reset reaction time becomes:

 $t_{rr} = t_{rd, int} + t_{rr, d}$

with

- *t*_{rr}: reset reaction time
- t_{rr,int}: internal reset reaction time
- *t*_{rr,d}: reset discharge

Optional Reset Output Pull-Up Resistor $R_{RO,ext}$:

The Reset Output RO is an open collector output with an integrated pull-up resistor. If needed, an external pull-up resistor to the output Q can be added. In **Table "Electrical Characteristics Reset Function" on Page 18** a minimum value for the external resistor $R_{\text{RO,ext}}$ is given.

Reset Adjust Function

The undervoltage reset switching threshold can be adjusted according to the application's needs by connecting an external voltage divider (R_{ADJ1} , R_{ADJ2}) at pin RADJ. For selecting the default threshold connect pin RADJ to GND.

When dimensioning the voltage divider, take into consideration that there will be an additional current constantly flowing through the resistors.

With a voltage divider connected, the reset switching threshold $V_{\text{RT,new}}$ is calculated as follows:

$$V_{RT, new} = \frac{R_{ADJ, 1} + R_{ADJ, 2}}{R_{ADJ, 2}} \times V_{RADJ, th}$$

with

- *V*_{RT.new}: the desired new reset switching threshold
- $R_{AD,1}$, $R_{AD,2}$: resistors of the external voltage divider
- V_{RADJ,th}: reset adjust switching threshold given in Table "Electrical Characteristics Reset Function" on Page 18



Block Description and Electrical Characteristics

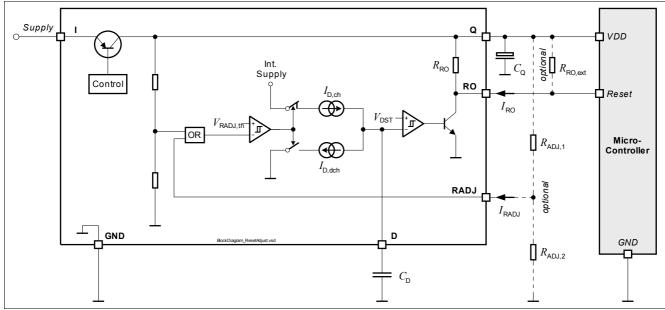


Figure 5 Block Diagram Reset Function



Block Description and Electrical Characteristics

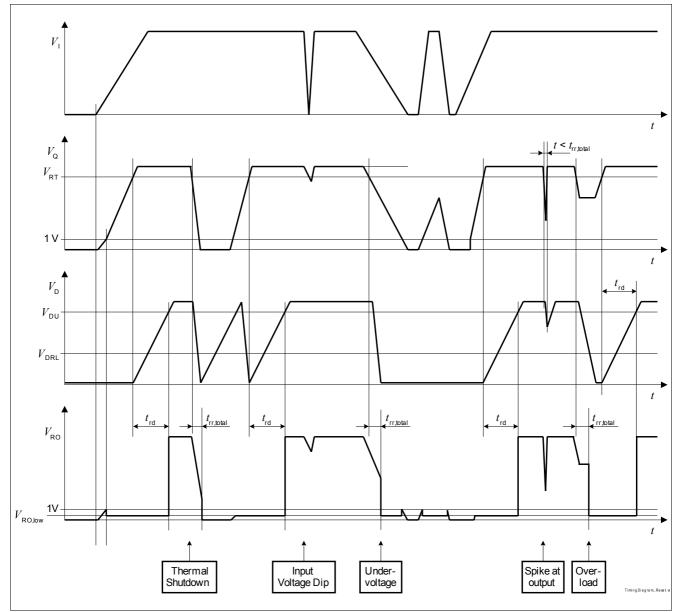


Figure 6 Timing Diagram Reset



Electrical Characteristics Reset Function

 $V_{\rm I}$ = 13.5 V, -40 °C $\leq T_{\rm j} \leq$ 150 °C, all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Pos.	Parameter	Symbol		Limit Val	ues	Unit	Conditions
			Min.	Тур.	Max.		
Output	Undervoltage Reset			i			
5.6.1	Default Output Undervoltage Reset Switching Thresholds	V _{RT}	3.00	3.10	3.20	V	$V_{\rm Q}$ decreasing
5.6.2	Output Undervoltage Reset Headroom	V _{RH}	50	200	300	mV	-
Output	Undervoltage Reset Threshold Ad	justment	1	1			
5.6.3	Reset Adjust Switching Threshold	$V_{RADJ,th}$	1.26	1.36	1.44	V	V _Q > 2.5 V
5.6.4	Reset Adjustment Range ¹⁾	$V_{\rm RT,range}$	2.50	_	3.10	V	-
Reset 0	Dutput RO	<u> </u>	_1				
5.6.5	Reset Output Low Voltage	$V_{\rm RO,low}$	-	0.1	0.4	V	1 V $\leq V_{Q} \leq V_{RT}$ no external $R_{RO,ext}$
5.6.6	Reset Output Internal Pull-up Resistor to $V_{\rm Q}$	R _{RO}	10	20	40	kΩ	-
5.6.7	Optional Reset Output External Pull-up Resistor to $V_{\rm Q}$	R _{RO,ext}	5.6	-	-	kΩ	$1 \text{ V} \le V_{\text{Q}} \le V_{\text{RT}};$ $V_{\text{RO}} \le 0.4 \text{ V}$
Reset [Delay Timing			I			
5.6.8	Delay Pin Output Voltage	VD	_	_	5	V	-
5.6.9	Power On Reset Delay Time	t _{rd}	36	51	60	ms	$C_{\rm D}$ = 100 nF Calculated Value: $t_{\rm rd}$ = $C_{\rm D}$ * $V_{\rm DU}$ / $I_{\rm D,ch}$
5.6.10	Upper Delay Switching Threshold	V _{DU}	-	1.85	-	V	-
5.6.11	Lower Delay Switching Threshold	V _{DL}	-	0.50	-	V	-
5.6.12	Delay Capacitor Charge Current	$I_{\rm D,ch}$	-	3.5	-	μA	<i>V</i> _D = 1 V
5.6.13	Delay Capacitor Reset Discharge Current	$I_{\rm D,dch}$	-	70	-	mA	<i>V</i> _D = 1 V
5.6.14	Delay Capacitor Discharge Time	t _{rr,d}	-	1.7	3.0	μs	Calculated Value: $t_{\rm rr,d} = C_{\rm D}^{*}(V_{\rm DU} - V_{\rm DL})/I_{\rm D,dch}$ $C_{\rm D} = 100 \text{ nF}$
5.6.15	Internal Reset Reaction Time	t _{rr,int}	-	20	25	μs	$C_{\rm D}$ = 0 nF ²⁾
5.6.16	Reset Reaction Time	t _{rr,total}	-	21.7	28	μs	Calculated Value: $t_{rr,total} = t_{rr,int} + t_{rr,d}$ $C_{D} = 100 \text{ nF}$

1) $V_{\rm RT}$ is scaled linearly, in case the Reset Switching Threshold is modified

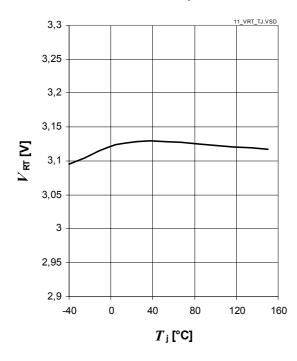
2) parameter not subject to production test; specified by design



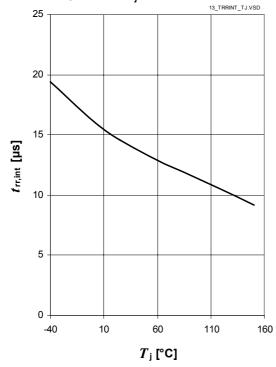
Block Description and Electrical Characteristics

5.7 Typical Performance Characteristics Reset

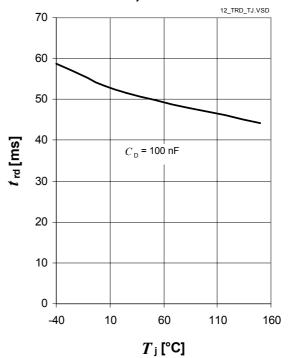
Undervoltage Reset Switching Threshold $V_{\rm RT}$ versus Junction Temperature $T_{\rm j}$



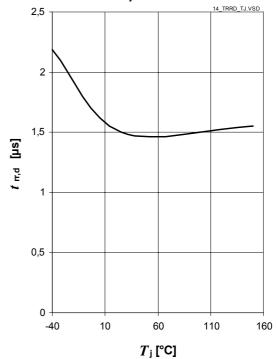
Internal Reset Reaction Time $t_{\rm rr,int}$ versus Junction Temperature $T_{\rm i}$



Power On Reset Delay Time t_{rd} versus Junction Temperature T_i



Delay Capacitor Discharge Time $t_{\rm rr,d}$ versus Junction Temperature $T_{\rm i}$



Data Sheet



5.8 Early Warning Function

The additional sense comparator provides an early warning function: Any voltage (e.g. the input voltage) can be monitored, an undervoltage condition is indicated by setting the comparator's output to low.

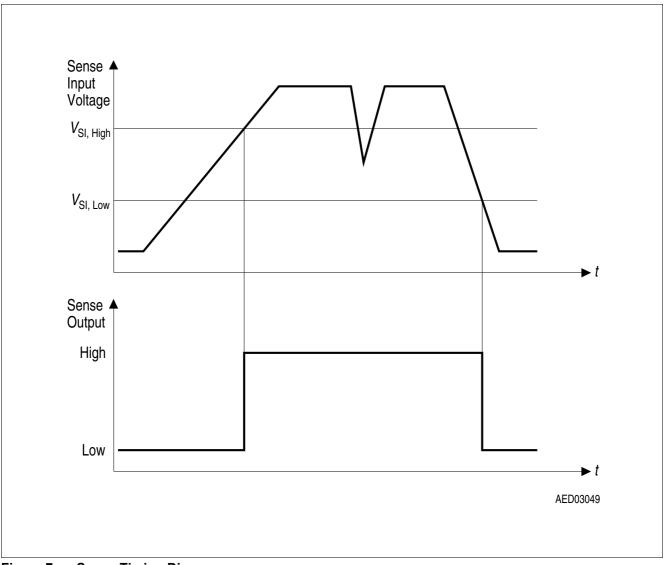


Figure 7 Sense Timing Diagram

Electrical Characteristics Early Warning Function

 $V_{\rm I}$ = 13.5 V, -40 °C $\leq T_{\rm j} \leq$ 150 °C, all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Pos.	Parameter	Symbol	Limit Values			Unit	Conditions	
			Min.	Тур.	Max.			
Sense	Comparator Input	<u>_</u>						
5.8.1	Sense Threshold High	$V_{\rm SI,high}$	1.34	1.45	1.54	V	-	
5.8.2	Sense Threshold Low	$V_{\rm SI,low}$	1.26	1.36	1.44	V	-	
5.8.3	Sense Switching Hysteresis	$V_{\rm SI,hy}$	50	90	130	mV	$V_{\rm SI,hy}$ = $V_{\rm SI,high}$ - $V_{\rm SI,low}$	
5.8.4	Sense Input Current	I _{SI}	-1	-0.1	1	μA	-	



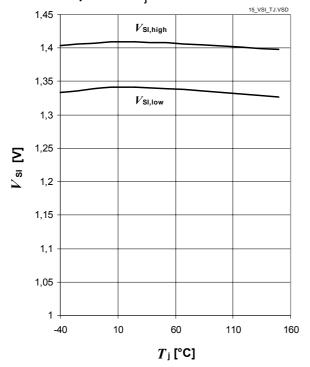
Electrical Characteristics Early Warning Function

 $V_{\rm I}$ = 13.5 V, -40 °C $\leq T_{\rm j} \leq$ 150 °C, all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Pos.	Parameter	Symbol	Limit Values			Unit	Conditions
			Min.	Тур.	Max.		
Sense	Comparator Output	1					
5.8.5	Sense Output Low Voltage	V _{SO,low}	-	0.1	0.4	V	$V_{SI} < V_{SI,low}$ $V_{I} > 4.4 V$ no external $R_{SO,ext}$
5.8.6	Sense Output Internal Pull-up Resistor to $V_{\rm Q}$	R _{SO}	10	20	40	kΩ	-
5.8.7	Optional Sense Output External Pull-up Resistor to $V_{\rm Q}$	R _{SO,ext}	5.6	-	-	kΩ	$V_{\rm I} > 4.4 \text{ V}$ $V_{\rm SO} \le 0.4 \text{ V}$

5.9 Typical Performance Characteristics Early Warning

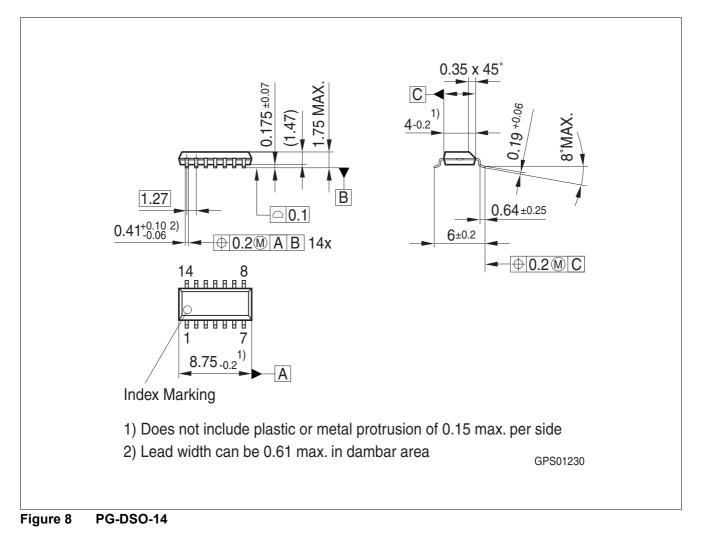
Sense Thresholds $V_{\rm SI,high}$, $V_{\rm SI,low}$ versus Junction Temperature $T_{\rm i}$





Package Outlines

6 Package Outlines





Package Outlines

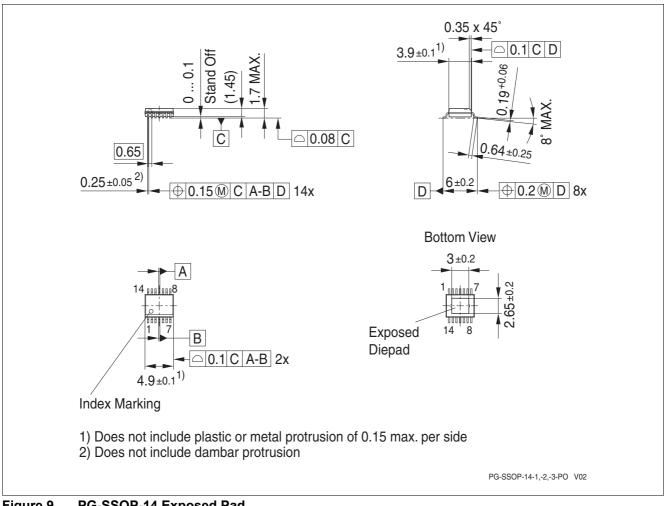


Figure 9 PG-SSOP-14 Exposed Pad

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

For further information on alternative packages, please visit our website: http://www.infineon.com/packages.



Revision History

7 Revision History

Revision	Date	Changes
1.01	2010-10-14	page 10, Pos. 5.1.1: Editorial change typ. 3.0 V corrected to 3.30 V
1.0	2010-10-01	initial version data sheet

Edition 2010-10-14

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